

#### General Description

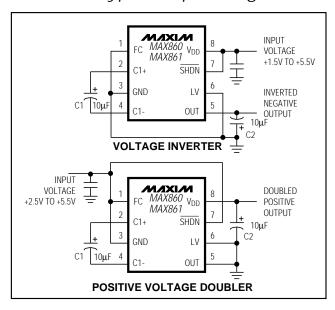
The MAX860/MAX861 charge-pump voltage converters invert input voltages ranging from +1.5V to +5.5V, or double input voltages ranging from +2.5V to +5.5V. Because of their high switching frequencies, these devices use only two small, low-cost capacitors. Their 50mA output makes switching regulators unnecessary, eliminating inductors and their associated cost, size, and EMI. Greater than 90% efficiency over most of the load-current range, combined with a typical operating current of only 200µA (MAX860), provides ideal performance for both battery-powered and board-level voltage-conversion applications.

A frequency-control (FC) pin provides three switchingfrequencies to optimize capacitor size and quiescent current and to prevent interference with sensitive circuitry. Each device has a unique set of three available frequencies. A shutdown (SHDN) pin reduces current consumption to less than 1µA. The MAX860/MAX861 are suitable for use in applications where the ICL7660 and MAX660's switching frequencies are too low. The MAX860/MAX861 are available in 8-pin µMAX and SO packages.

**Applications** 

Portable Computers Medical Instruments Interface Power Supplies Hand-Held Instruments Operational-Amplifier Power Supplies

## Typical Operating Circuit



**Features** 

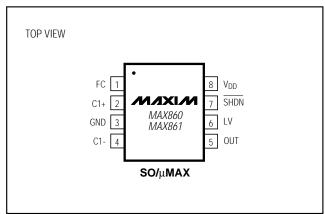
- ♦ 8-Pin, 1.11mm High µMAX Package
- ♦ Invert or Double the Input Supply Voltage
- ♦ Three Selectable Switching Frequencies
- **♦ High Frequency Reduces Capacitor Size**
- ♦ 87% Efficiency at 50mA
- ♦ 200µA Quiescent Current (MAX860)
- **♦ 1µA Shutdown Supply Current**
- ♦ 600mV Voltage Drop at 50mA Load
- **♦ 12**Ω Output Resistance

#### Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX860ISA	-25°C to +85°C	8 SO
MAX860IUA	-25°C to +85°C	8 µMAX
MAX860C/D	0°C to +70°C	Dice*
MAX860ESA	-40°C to +85°C	8 SO
MAX860MJA	-55°C to +125°C	8 CERDIP <sup>†</sup>
MAX861ISA	-25°C to +85°C	8 SO
MAX861IUA	-25°C to +85°C	8 µMAX
MAX861C/D	0°C to +70°C	Dice*
MAX861ESA	-40°C to +85°C	8 SO
MAX861MJA	-55°C to +125°C	8 CERDIP <sup>†</sup>

- \* Dice are tested at  $T_A = +25$ °C, DC parameters only.
- † Contact factory for availability.

## Pin Configuration



NIXIN

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#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage (V <sub>DD</sub> to GND or GND to OUT). Input Voltage Range (LV, FC, SHDN)	
Continuous Output Current (OUT, V <sub>DD</sub> ) Output Short-Circuit to GND (Note 1) Continuous Power Dissipation (T <sub>A</sub> = +70°C)	60mÁ
SO (derate 5.88mW/°C above +70°C)μMAX (derate 4.10mW/°C above +70°C) CERDIP (derate 8.00mW/°C above +70°C)	330mW

Operating Temperature Ranges	
MAX86_I_A	25°C to +85°C
MAX86_ESA	40°C to +85°C
MAX86_MJA	55°C to +125°C
Storage Temperature Range	65°C to +160°C
Lead Temperature (soldering, 10	sec)+300°C

**Note 1:** OUT may be shorted to GND for 1sec without damage, but shorting OUT to V<sub>DD</sub> may damage the device and should be avoided. Also, for temperatures above +85°C, OUT must not be shorted to GND or V<sub>DD</sub>, even instantaneously, or device damage may result.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

(Typical Operating Circuit (Inverter),  $V_{DD} = +5V$ ,  $\overline{SHDN} = V_{DD}$ , FC = LV = GND,  $C1 = C2 = 10\mu F$  (Note 2),  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	СО	NDITIONS	MIN	TYP	MAX	UNITS
Cupply Voltage	Voo	$R_L = 1k\Omega$	Inverter, LV = GND	1.5		5.5 5.5	\/
Supply Voltage	V <sub>DD</sub>	KC = 1K77	Doubler, LV = OUT	2.5			\ \ \ \ \
			FC = V <sub>DD</sub> = 5V		0.2	0.3	
		MAX860I/E	$FC = V_{DD} = 3V$		0.07		
		IVIAAOOUI/E	FC = GND		0.6	1.0	
			FC = OUT		1.4	2.5	
			FC = V <sub>DD</sub>			0.4	]
		MAX860M	FC = GND			1.3	mA
No-Load Supply Current	IDD		FC = OUT			3.3	
		MAX8611/E	FC = V <sub>DD</sub>		0.3	0.4	
			FC = GND		1.1	2.0	
			FC = OUT		2.5	5.0	
		MAX861M	FC = V <sub>DD</sub>			0.5	
			FC = GND			2.6	
			FC = OUT			6.5	
Output Current	ЮП	V <sub>DD</sub> = 5V, V <sub>OUT</sub> ma	ore negative than -3.75V	50	100		— mA
output Guirent	1001	VDD = 3V, VOUT mor	ore negative than -2.5V	10	30		
Output Resistance	Rout	IL = 50mA			12	25	Ω
(Note 3)	NOUT	IL = 10mA, V <sub>DD</sub> = 2	2V		20	35	22

### **ELECTRICAL CHARACTERISTICS (continued)**

(Typical Operating Circuit (Inverter),  $V_{DD} = +5V$ ,  $\overline{SHDN} = V_{DD}$ , FC = LV = GND,  $C1 = C2 = 10\mu F$  (Note 2),  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25$ °C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
			FC = V <sub>DD</sub>	3	6			
		MAX860	FC = GND	30	50		kHz	
Switching Frequency	fs		FC = OUT	80	130			
(Note 4)	15		FC = V <sub>DD</sub>	8	13		NIIZ	
		MAX861	FC = GND	60	100		1	
			FC = OUT	160	250			
FC Current (from V <sub>DD</sub> )	I <sub>FC</sub>	FC < 4V	-		-2	-4	μΑ	
		MAX860,	$R_L = 2k\Omega$ from $V_{DD}$ to $OUT$	93	96			
	MA	FC = V <sub>DD</sub>	$R_L = 1k\Omega$ from OUT to GND	90	93			
Power Efficiency (Note 5)		MAX861, FC = V <sub>DD</sub>	$R_L = 2k\Omega$ from $V_{DD}$ to OUT	93	96		%	
			$R_L = 1k\Omega$ from OUT to GND	88	92			
		MAX860/MAX861, FC I <sub>L</sub> = 50mA to GND, C1			87			
Voltage-Conversion Efficiency		No load		99	99.9		%	
SHDN Threshold	VIH	LV = GND		1.2			V	
SHDN Threshold	VIL					0.3	]	
Shutdown Supply Current		<u>SHDN</u> < 0.3V	MAX86_I/E			1	μΑ	
Shataown Supply Current		311DIV \ 0.3V	MAX86_M			10	μΛ	
Time to Exit Shutdown		No load, Vout = -4V			500		μs	

Note 2: C1 and C2 are low-ESR ( $<0.2\Omega$ ) aluminum electrolytics. Capacitor ESR adds to the circuit's output resistance. Using capacitors with higher ESR may reduce output voltage and efficiency.

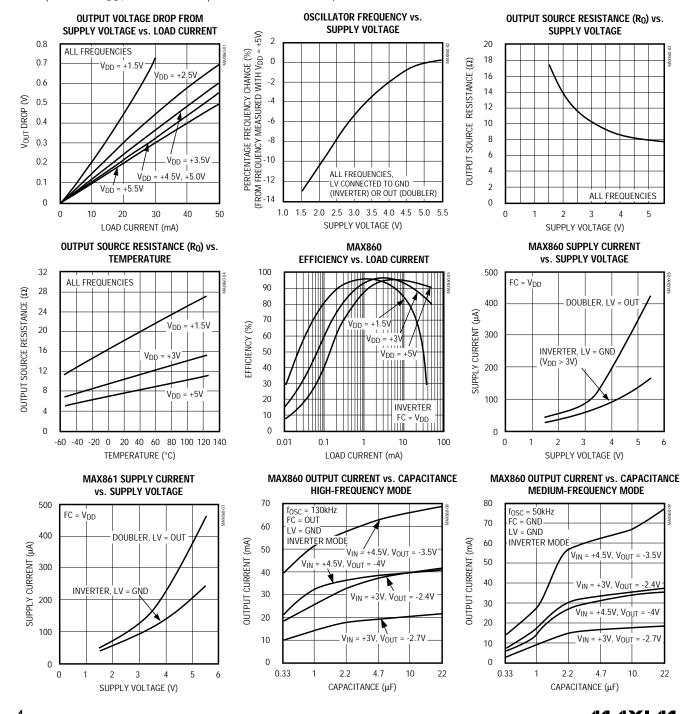
**Note 3:** Specified output resistance includes the effect of the  $0.2\Omega$  ESR of the test circuit's capacitors.

**Note 4:** The switches are driven directly at the oscillator frequency, without any division.

Note 5: At lowest frequencies, using 10µF capacitors gives worse efficiency figures than using the recommended capacitor values in Table 3, due to larger 1 / (f<sub>s</sub> x C1) term in R<sub>OUT</sub>.

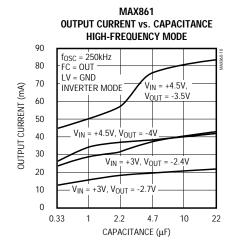
### Typical Operating Characteristics

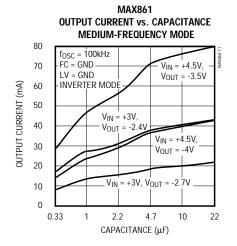
(All curves generated using the inverter circuit shown in the *Typical Operating Circuits* with LV = GND and  $T_A = +25^{\circ}C$ , unless otherwise noted. Test results also valid for doubler mode with LV = OUT and  $T_A = +25^{\circ}C$ . All capacitor values used are those recommended in Table 3, unless otherwise noted. The output resistance curves represent the resistance of the device itself, which is Ro in the equation for  $R_{OUT}$  shown in the *Capacitor Selection* section.)



## Typical Operating Characteristics (continued)

(All curves generated using the inverter circuit shown in the *Typical Operating Circuits* with LV = GND and  $T_A = +25^{\circ}C$ , unless otherwise noted. Test results also valid for doubler mode with LV = OUT and  $T_A = +25^{\circ}C$ . All capacitor values used are those recommended in Table 3, unless otherwise noted. The output resistance curves represent the resistance of the device itself, which is Ro in the equation for R<sub>OUT</sub> shown in the *Capacitor Selection* section.)





### Pin Description

PIN	NAME	FUNCTION			
FIN	INAIVIE	INVERTER	DOUBLER		
1	FC	Frequency Control, see Table 1	Frequency Control, see Table 1		
2	C1+	Flying-Capacitor Positive Terminal	Flying-Capacitor Positive Terminal		
3	GND	Ground	Positive Input Supply		
4	C1-	Flying-Capacitor Negative Terminal	Flying-Capacitor Negative Terminal		
5	OUT	Negative Output	Ground		
6	LV	Low-Voltage-Operation Input. Connect to GND.	Low-Voltage-Operation Input. Connect to OUT.		
7	SHDN	Active-Low Shutdown Input. Connect to V <sub>DD</sub> if not used. Connect to GND to disable the charge pump.	Active-Low Shutdown Input. Connect to GND pin if not used. Connect to OUT to disable the charge pump.		
8	V <sub>DD</sub>	Positive Input Supply	Doubled Positive Output		

#### \_Detailed Description

The MAX860/MAX861 capacitive charge pumps either invert or double the voltage applied to their inputs. For highest performance, use low equivalent series resistance (ESR) capacitors. See the *Capacitor Selection* section for more details. The frequency-control (FC) pin allows you to choose one of three switching frequencies; these three selectable frequencies are different for each device. When shut down, MAX860/MAX861 current consumption reduces to less than 1µA.

#### Common Applications

#### Voltage Inverter

The most common application for these devices is a charge-pump voltage inverter (see *Typical Operating Circuits*). This application requires only two external components—capacitors C1 and C2—plus a bypass capacitor if necessary (see *Bypass Capacitor* section). Refer to the *Capacitor Selection* section for suggested capacitor types and values.

Even though the MAX860/MAX861's output is not actively regulated, it is fairly insensitive to load-current changes. A circuit output source resistance of  $12\Omega$  (calculated using the formula given in the *Capacitor Selection* section) means that, with a +5V input, the output voltage is -5V under no load and decreases to -4.4V with a 50mA load. The MAX860/MAX861 output source resistance (used to calculate the circuit output source resistance) vs. temperature and supply voltage are shown in the *Typical Operating Characteristics* graphs.

Calculate the output ripple voltage using the formula given in the *Capacitor Selection* section.

#### Positive Voltage Doubler

The MAX860/MAX861 can also operate as positive voltage doublers (see *Typical Operating Circuits*). This application requires only two external components, capacitors C1 and C2. The no-load output is twice the input voltage. The electrical specifications in the doubler mode are very similar to those of the inverter mode except for the Supply Voltage Range (see *Electrical Characteristics* table) and No-Load Supply Current (see graph in *Typical Operating Characteristics*). The circuit output source resistance and output ripple voltage are calculated using the formulas in the *Capacitor Selection* section.

#### Active-Low Shutdown Input

When driven low, the SHDN input shuts down the device. In inverter mode, connect SHDN to V<sub>DD</sub> if it is not used. In doubler mode, connect SHDN to GND if it

is not used. When the device is shut down, all active circuitry is turned off.

In the inverting configuration, loads connected from OUT to GND are not powered in shutdown mode. However, a reverse-current path exists through two diodes between OUT and GND; therefore, loads connected from  $V_{DD}$  to OUT draw current from the input supply.

In the doubling configuration, loads connected from the  $V_{DD}$  pin to the GND pin are not powered in shutdown mode. Loads connected from the  $V_{DD}$  pin to the OUT pin draw current from the input supply through a path similar to that of the inverting configuration (described above).

#### Frequency Control

Charge-pump frequency for both devices can be set to one of three values. Each device has a unique set of three available frequencies, as indicated in Table 1. The oscillator and charge-pump frequencies are the same (i.e., the charge-pump frequency is not half the oscillator frequency, as it is on the MAX660, MAX665, and ICL7660).

Table 1. Nominal Switching Frequencies\*

FC CONNECTION	FREQUENCY (kHz)		
FC CONNECTION	MAX860	MAX861	
FC = V <sub>DD</sub> or open	6	13	
FC = GND	50	100	
FC = OUT	130	250	

\*See the Electrical Characteristics for detailed switching-frequency specifications.

A higher switching frequency minimizes capacitor size for the same performance and increases the supply current (Table 2). The lowest fundamental frequency of the switching noise is equal to the minimum specified switching frequency (e.g., 3kHz for the MAX860 with FC open). The spectrum of noise frequencies extends above this value because of harmonics in the switching waveform. To get best noise performance, choose the device and FC connection to select a minimum switching frequency that lies above your sensitive bandwidth.

#### Low-Voltage-Operation Input

LV should be connected to GND for inverting operation. To enhance compatibility with the MAX660, MAX665, and ICL7660, you may float LV if the input voltage exceeds 3V. In doubling mode, LV must be connected to OUT for all input voltages.

Table 2. Switching-Frequency Trade-Offs

ATTRIBUTE	LOWER FREQUENCY	HIGHER FREQUENCY
Output Ripple	Larger	Smaller
C1, C2 Values	Larger	Smaller
Supply Current	Smaller	Larger

### \_Applications Information

Capacitor Selection

The MAX860/MAX861 are tested using 10µF capacitors for both C1 and C2, although smaller or larger values can be used (Table 3). Smaller C1 values increase the output resistance; larger values reduce the output resistance. Above a certain point, increasing the capacitance of C1 has a negligible effect (because the output resistance becomes dominated by the internal switch resistance and the capacitor ESR). Low-ESR capacitors provide the lowest output resistance and ripple voltage. The output resistance of the entire circuit (inverter or doubler) is approximately:

$$ROUT = RO + 4 \times ESRC1 + ESRC2 + 1 / (fs \times C1)$$

where R<sub>O</sub> (the effective resistance of the MAX860/ MAX861's internal switches) is approximately  $8\Omega$  and fg is the switching frequency. R<sub>OUT</sub> is typically  $12\Omega$  when using capacitors with  $0.2\Omega$  ESR and fg, C1, and C2 values suggested in Table 3. When C1 and C2 are so large (or the switching frequency is so high) that the internal switch resistance dominates the output resistance, estimate the output resistance as follows:

 $ROUT = RO + 4 \times ESRC1 + ESRC2$ 

A typical design procedure is as follows:

- 1) Choose C1 and C2 to be the same, for convenience.
- 2) Select fs:
  - a) If you want to avoid a specific noise frequency, choose fs appropriately.
  - b) If you want to minimize capacitor cost and size, choose a high fs.
  - c) If you want to minimize current consumption, choose a low fs.
- Choose a capacitor based on Table 3, although higher or lower values can be used to optimize performance. Table 4 lists manufacturers who provide low-ESR capacitors.

Table 3. Suggested Capacitor Values\*

NOMINAL FREQUENCY (kHz)	C1, C2 (μF)
6	68
13	47
50	10
100	4.7
130	4.7
250	2.2

\*In addition to Table 3, four graphs in the *Typical Operating Characteristics* section show typical output current for C1 and C2 capacitances ranging from  $0.33\mu F$  to  $22\mu F$ . Output current is plotted for inputs of 4.5V (5V - 10%) and 3.0V (3.3V - 10%), and also for 10% and 20% output droop from the ideal -V<sub>IN</sub> value.

**Table 4. Low-ESR Capacitor Manufacturers** 

MANUFACTURER-Series	PHONE	FAX	COMMENTS
AVX TPS Series	(803) 946-0629	(803) 626-3123	Low-ESR tantalum, SMT
AVX TAG Series	(803) 946-0629	(803) 626-3123	Low-cost tantalum, SMT
Matsuo 267 Series	(714) 969-2491	(714) 960-6492	Low-cost tantalum, SMT
Sprague 595 Series	(603) 224-1961	(613) 224-1430	Low-ESR tantalum, SMT
Sanyo MV-GX Series	(619) 661-6835	(619) 661-1055	Aluminum electrolytic, through hole
Sanyo CV-GX Series	(619) 661-6835	(619) 661-1055	Aluminum electrolytic, SMT
Nichicon PL Series	(847) 843-7500	(847) 843-2798	Aluminum electrolytic, through hole
United Chemicon (Marcon)	(847) 696-2000	(847) 696-9278	Ceramic SMT
TDK	(847) 390-4461	(847) 390-4405	Ceramic SMT

#### Flying Capacitor, C1

Increasing the size of the flying capacitor reduces the output resistance.

#### Output Capacitor, C2

Increasing the size of the output capacitor reduces the output ripple voltage. Decreasing its ESR reduces both output resistance and ripple. Smaller capacitance values can be used if one of the higher switching frequencies is selected, if less than the maximum rated output current (50mA) is required, or if higher ripple can be tolerated. The following equation for peak-to-peak ripple applies to both the inverter and doubler circuits.

$$V_{RIPPLE} = \frac{I_{OUT}}{2 \text{ x f}_{S} \text{ x C2}} + 2 \text{ x I}_{OUT} \text{ x ESR}_{C2}$$

#### **Bypass Capacitor**

Bypass the incoming supply to reduce its AC impedance and the impact of the MAX860/MAX861's switching noise. The recommended bypassing depends on the circuit configuration and where the load is connected.

When the inverter is loaded from OUT to GND or the doubler is loaded from V<sub>DD</sub> to GND, current from the supply switches between 2 x I<sub>OUT</sub> and zero. Therefore, use a large bypass capacitor (e.g., equal to the value of C1) if the supply has a high AC impedance.

When the inverter and doubler are loaded from V<sub>DD</sub> to OUT, the circuit draws 2 x  $I_{OUT}$  constantly, except for short switching spikes. A  $0.1\mu F$  bypass capacitor is sufficient.

#### Cascading Devices

Two devices can be cascaded to produce an even larger negative voltage, as shown in Figure 1. The

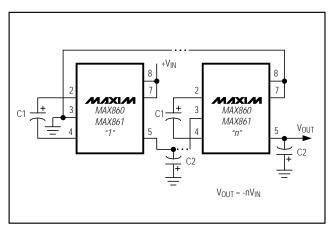


Figure 1. Cascading MAX860s or MAX861s to Increase Output Voltage

unloaded output voltage is nominally -2 x V<sub>IN</sub>, but this is reduced slightly by the output resistance of the first device multiplied by the quiescent current of the second. The output resistance of the complete circuit is approximately *five times* the output resistance of a single MAX860/MAX861.

Three or more devices can be cascaded in this way, but output resistance rises dramatically, and a better solution is offered by inductive switching regulators (such as the MAX755, MAX759, MAX764, or MAX774). Connect LV as with a standard inverter circuit (see *Pin Description*).

#### Paralleling Devices

Paralleling multiple MAX860s or MAX861s reduces the output resistance. As illustrated in Figure 2, each device requires its own pump capacitor (C1), but the reservoir capacitor (C2) serves all devices. C2's value should be increased by a factor of n, where n is the number of devices. Figure 2 shows the equation for calculating output resistance. An alternative solution is to use the MAX660 or MAX665, which are capable of supplying up to 100mA of load current. Connect LV as with a standard inverter circuit (see *Pin Description*).

#### Combined Doubler/Inverter

In the circuit of Figure 3, capacitors C1 and C2 form the inverter, while C3 and C4 form the doubler. C1 and C3 are the pump capacitors; C2 and C4 are the reservoir capacitors. Because both the inverter and doubler use part of the charge-pump circuit, loading either output causes both outputs to decline towards GND. Make sure the sum of the currents drawn from the two outputs does not exceed 60mA. Connect LV as with a standard inverter circuit (see *Pin Description*).

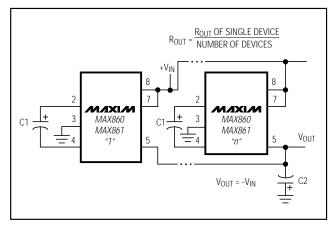


Figure 2. Paralleling MAX860s or MAX861s to Reduce Output Resistance

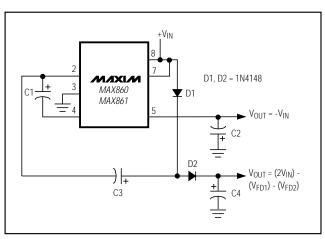


Figure 3. Combined Doubler and Inverter

# Compatibility with MAX660/MAX665/ICL7660

The MAX860/MAX861 can be used in sockets designed for the MAX660, MAX665, and ICL7660 with a minimum of one wiring change. This section gives advice on installing a MAX860/MAX861 into a socket designed for one of the earlier devices.

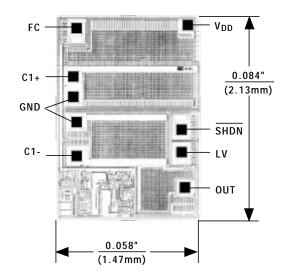
The MAX660, MAX665, and ICL7660 have an OSC pin instead of SHDN. MAX660, MAX665, and ICL7660 normal operation is with OSC floating (although OSC can be overdriven). If OSC is floating, pin 7 (SHDN) should be jumpered to VDD to enable the MAX860/MAX861 permanently. Do not leave SHDN on the MAX860/MAX861 floating.

The MAX860/MAX861 operate with FC either floating or connected to V<sub>DD</sub>, OUT, or GND; each connection defines the oscillator frequency. Thus, any of the normal MAX660, MAX665, or ICL7660 connections to pin 1 will work with the MAX860/MAX861, without modifications. Changes to the FC connection are only required if you want to adjust the operating frequency.

**Table 5. Product Selection Guide** 

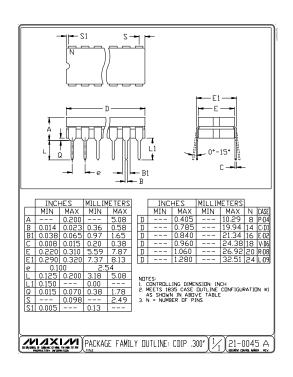
PART NUMBER	OUTPUT CURRENT (mA)	OUTPUT RESISTANCE (Ω)	SWITCHING FREQUENCY (kHz)
MAX660	100	6.5	5/40
MAX665	100	6.5	5/40
MAX860	50	12	6/50/130
MAX861	50	12	13/100/250
ICL7660	10	55	5

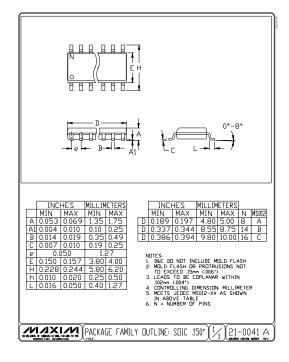
Chip Topography



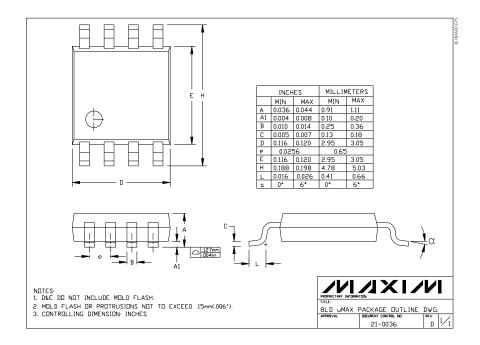
TRANSISTOR COUNT: 101
SUBSTRATE CONNECTED TO VDD

Package Information





Package Information (continued)



### **NOTES**

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.